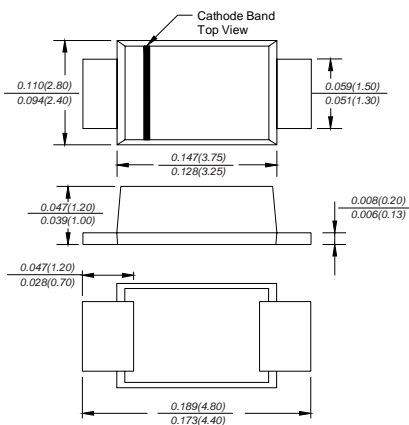


# SS32F THRU SS3200F

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

*Reverse Voltage - 20 to 200 Volts    Forward Current - 3.0 Amperes*

### SMAF



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 260°C/10 seconds at terminals

### MECHANICAL DATA

**Case:** JEDEC SMAF molded plastic body  
**Terminals:** leads solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

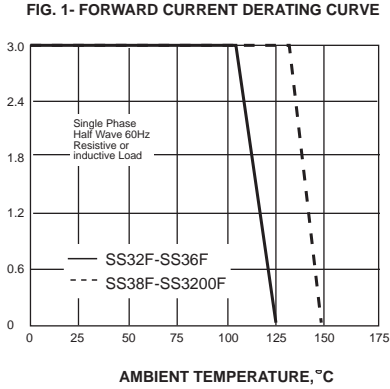
Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	SS32F	SS33F	SS34F	SS35F	SS36F	SS38F	SS310F	SS3150F	SS3200F	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	45	50	60	80	100	150	200	VOLTS
Maximum RMS voltage	$V_{RMS}$	14	21	31	35	42	56	70	105	150	VOLTS
Maximum DC blocking voltage	$V_{DC}$	20	30	45	50	60	80	100	150	200	VOLTS
Maximum average forward rectified current at $T_L$ (see fig. 1)	$I_{(AV)}$	3.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	80.0									Amps
Maximum instantaneous forward voltage at 3.0A	$V_F$	0.55			0.70		0.85		0.95		Volts
Maximum DC reverse current at rated DC blocking voltage	$I_R$	0.5						0.2		mA	
$T_A=25^\circ\text{C}$ $T_A=100^\circ\text{C}$		20			10		2.0				
Typical junction capacitance (NOTE 1)	$C_J$	500			300						pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	55.0									°C/W
Operating junction temperature range	$T_J$	-65 to +125						-65 to +150			°C
Storage temperature range	$T_{STG}$	-65 to +150									°C

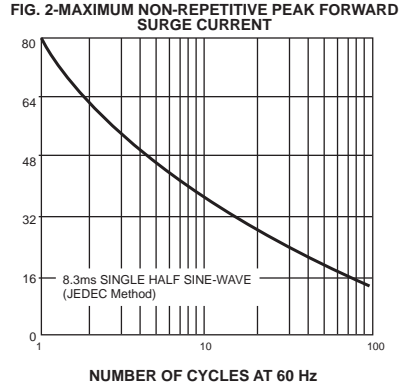
- Note:**
1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
  2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas
  3. ESD conforms to Country Standard(10KV).

# RATINGS AND CHARACTERISTIC CURVES SS32F THRU SS3200F

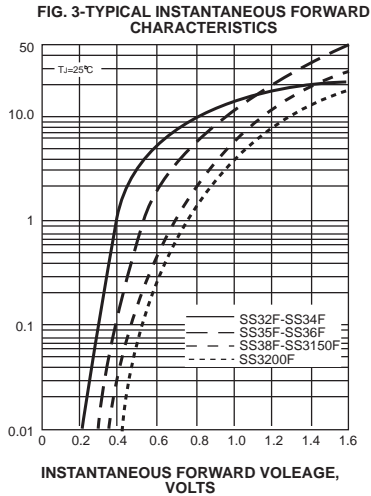
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES



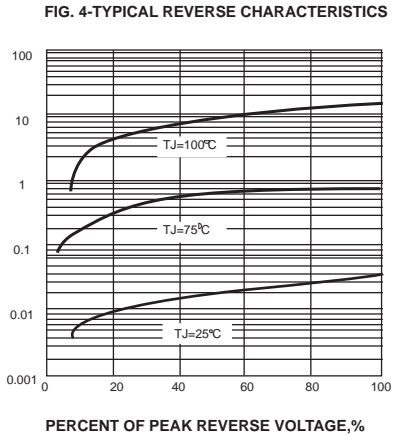
PEAK FORWARD SURGE CURRENT, AMPERES



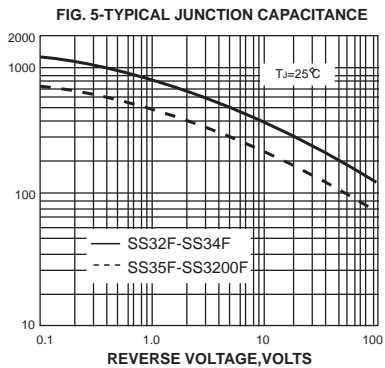
INSTANTANEOUS FORWARD CURRENT, AMPERES



INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE, °C/W

